

Schottky Diode

SBL1030

30V / 10A

DATASHEET

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OEM – General Semiconductor

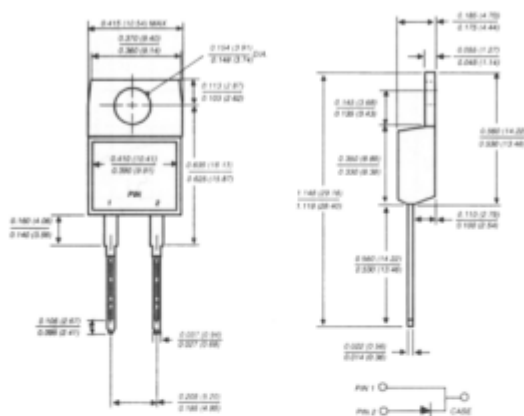
Source: General Semiconductor Databook 1998

SBL1030 AND SBL1040

SCHOTTKY RECTIFIER

Reverse Voltage - 30 and 40 Volts Forward Current - 10.0 Amperes

TO-220AC



Dimensions in inches and (millimeters)

FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guardring for overvoltage protection
- ◆ High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

MECHANICAL DATA

Case: JEDEC TO-220AC molded plastic body
Terminals: Leads solderable per MIL-STD-750, Method 2026
Polarity: As marked
Mounting Position: Any
Mounting Torque: 5 in. - lbs. max.
Weight: 0.08 ounces, 2.24 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	SBL1030	SBL1040	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	30	40	Volts
Maximum RMS voltage	V_{RMS}	21	28	Volts
Maximum DC blocking voltage	V_{DC}	30	40	Volts
Maximum average forward rectified current at $T_C=110^\circ C$	$I_{(AV)}$	10.0		Amps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	250.0		Amps
Maximum instantaneous forward voltage at 10A (NOTE 1)	V_F	0.55		Volts
Maximum instantaneous reverse current at rated DC blocking voltage (NOTE 1)	I_R	1.0 50.0		mA
Typical thermal resistance (NOTE 2)	$R_{\theta JC}$	2.0		$^\circ C/W$
Operating and storage temperature range	T_J, T_{STG}	-40 to +125		$^\circ C$

NOTES:

- (1) Pulse test: 300µs pulse width, 1% duty cycle
- (2) Thermal resistance from junction to case per leg

RATINGS AND CHARACTERISTIC CURVES SBL1030 AND SBL1040

